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Spin Curves for MicroChem S1800 (1805, 1813, 1818) Series Positive Resist

Abstract

Spin curves for MicroChem's S1805, S1813, and S1818 were generated and mapped using the Filmetrics F50. Statistical measurements were performed (N=85) and are reported here.

Keywords

S1805, S1813, S1818, S1805, 1813, 1818, MicroChem, spin curves, Shipley, spin curve, resist, positive resist, resist thickness, spin speed

Disciplines

Electrical and Electronics | Electronic Devices and Semiconductor Manufacturing | Nanotechnology Fabrication



Goal:

This report documents the spin curves for MicroChem S1805, S1813, S1818 series resist.

Materials:

- MicroChem S1805, S1813 and S1818 positive resist.
- A total of 36 4" Si wafers

Equipment:

- ReynoldsTech Spinner
- Torrey Pines Scientific Hotplate
- Filemetrics F50

Protocol:

<u>Coat</u>

- 1. Mount wafer and ensure that it is centered.
- 2. Deposit approximately 7 milliliters of S1800 series photoresist in the center of the wafer.
- 3. Spin wafer at 500 RPM for 60 seconds.
- 4. Repeat Step 3 at 500 RPM intervals up to 6000 RPM with a fresh wafer.

Soft Bake

1. Bake wafer at 115 °C for 60 seconds and allow wafer to cool after removal.

Measurement

- 1. Allow the Filmetrics F50 light to warm up for at least 5 minutes.
- 2. Click *Baseline...* to calibrate the tool using the SiO_2 and Si standards.
- 3. Mount wafer and select the *S1800 on Si* recipe.
- 4. Edit the recipe so that 85 points are measured on the wafer with a 1 cm edge exclusion.
- 5. Click Start to measure the resist thickness of each wafer.

Results:





S1800 Series Photoresist Spin Curve

Crain Crassed [DDM]	Thickness [μm] for S1805					
Spin Speed [RPivi]	Mean	Minimum	Maximum	Standard Deviation	Standard Error	
500	1.287	1.226	1.508	0.023	0.002	
1000	0.914	0.873	0.943	0.015	0.002	
1500	0.742	0.710	0.802	0.014	0.002	
2000	0.644	0.620	0.665	0.010	0.001	
2500	0.569	0.549	0.584	0.009	0.001	
3000	0.524	0.502	0.594	0.012	0.001	
3500	0.490	0.464	0.510	0.011	0.001	
4000	0.459	0.436	0.480	0.012	0.001	
4500	0.438	0.419	0.455	0.008	0.001	
5000	0.420	0.396	0.432	0.010	0.001	
5500	0.409	0.395	0.420	0.006	0.001	
6000	0.399	0.283	0.410	0.006	0.001	

Spin Speed (DDM)	Thickness [µm] for S1813					
Spiri Speed [KFIVi]	Mean	Minimum	Maximum	Standard Deviation	Standard Error	
500	4.387	0.294	5.971	0.758	0.082	
1000	3.161	2.023	3.271	0.133	0.014	
1500	2.596	2.504	3.618	0.129	0.014	
2000	2.183	1.433	2.318	0.168	0.018	
2500	1.937	1.293	1.993	0.074	0.008	
3000	1.604	1.547	1.751	0.031	0.003	
3500	1.479	1.440	1.697	0.035	0.004	
4000	1.389	1.353	1.438	0.019	0.002	
4500	1.318	1.280	1.650	0.042	0.004	
5000	1.265	1.218	1.648	0.050	0.005	
5500	1.203	1.164	1.384	0.031	0.003	
6000	1.157	1.120	1.203	0.015	0.002	

Spin Speed (DDM)	Thickness [µm] for S1818					
Spin Speed [KPivi]	Mean	Minimum	Maximum	Standard Deviation	Standard Error	
500	5.830	3.355	6.000	0.321	0.035	
1000	4.121	2.577	4.357	0.191	0.021	
1500	3.362	3.225	3.679	0.058	0.006	
2000	2.882	1.373	4.627	0.284	0.031	
2500	2.558	2.454	2.804	0.046	0.005	
3000	2.381	2.273	4.249	0.218	0.024	
3500	2.162	2.104	2.257	0.031	0.003	
4000	2.032	1.978	2.169	0.037	0.004	
4500	1.911	1.241	2.101	0.084	0.009	
5000	1.776	1.699	2.131	0.066	0.007	
5500	1.735	1.150	2.001	0.081	0.009	
6000	1.673	1.631	1.936	0.042	0.004	

Revision: url:

The wafer map of specified measurements for \$1805, \$1813 and \$1818 photoresist are shown below.

The thickness achieved by spinning the wafers at 5000RPM (nominal speed) is less than expected for S1805 and S1813. The nominal thickness is achieved at lower spin speeds for those two resists.

Fig. 2 shows the F50 measurement for S1805 spun at 5000RPM and as it could be seen the thickness was roughly 0.42µm (nominal thickness of 0.5µm was *not* achieved).

Fig.3 shows the F50 measurement for S1805 spun at 3500RPM which gives the nominal thickness of $0.5 \mu m$.





S1800 Series Photoresist Spin Curve





Fig. 4 shows the F50 measurement for S1813 spun at 5000RPM which gives the thickness of 1.26μm (nominal thickness of 1.3μm was *not* achieved).

Fig. 5 shows the F50 measurement for S1813 spun at 4500RPM which gives the nominal thickness of 1.3µm.

WaferMap	Measure	History
1.648 μm 1.648 μm 1.605 μm 1.562 μm 1.562 μm 1.562 μm 1.204 1.344 1.519 μm 1.476 μm 1.476 μm 1.476 μm 1.256 1.254 1.300 μm 1.244 1.235 1.218 μm 1.218 μm 1.224 1.224 1.224 1.224	1281 1.272 1.274 1281 1272 1.278 1228 1231 1288 1283 1228 1231 1288 1200 1270 128 1255 1265 1252 1274 1258 1292 1285 1274 1252 1273 1292 1278 1282 1261 1273 1292 1278 1292 1276 1284 1242 1241 1254 1247 1247 1242 1241 1254 1247 1247 1242 1241 1254 1257 1257 1261 1242 1241 1254 1247 1247 1248 1251 1263 1242 1243 1254 1251 1263 1249 1251 1263 1242 1254 1234 1248 1249 1249 1249 1249 1242 1254 1241 1246 1249 1249 1249 1249 1242 1254 1251 <th>Age Information ID Date 6/9/2016 4.05 22 PM File 12016_06_09-16_06_0 Display Parameter to Display: Site 1Layer 1 Thickness ▼ 2D 3D ♥ Show Color ♥ Show Points ♥ Show Values Manual Color Color Scale Range Min 12179 µm Max 1.64764 µm Replot Results Min: 1218 µm Max 1.64764 µm Max 1.648 µm Max: 1265 µm Std Dev: 0.05022 µm Uniformity: +/ 17.0% CTE: 0.01089 µm Wedge Ang: 911 Valid: 85/85 Alarmed: N/A</th>	Age Information ID Date 6/9/2016 4.05 22 PM File 12016_06_09-16_06_0 Display Parameter to Display: Site 1Layer 1 Thickness ▼ 2D 3D ♥ Show Color ♥ Show Points ♥ Show Values Manual Color Color Scale Range Min 12179 µm Max 1.64764 µm Replot Results Min: 1218 µm Max 1.64764 µm Max 1.648 µm Max: 1265 µm Std Dev: 0.05022 µm Uniformity: +/ 17.0% CTE: 0.01089 µm Wedge Ang: 911 Valid: 85/85 Alarmed: N/A



S1800 Series Photoresist Spin Curve







Fig. 6 shows the F50 measurement for S1818 spun at 5000RPM (nominal thickness of 1.8µm was achieved)